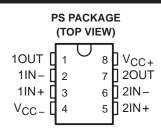
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- Wide Range of Supply Voltages; Single Supply . . . 3 V to 36 V, or Dual Supplies
- Class AB Output Stage
- High-Impedance N-Channel-JFET Input Stage . . . $10^{12} \Omega$ Typ
- Internal Frequency Compensation
- Short-Circuit Protection
- Input Common Mode Includes V_{CC}
- Low Input Offset Current . . . 50 pA
- Low Input Bias Current . . . 200 pA Typ



description

The TL092 JFET-input operational amplifier is similar in performance to the MC3403 family, but with much higher input impedance derived from a FET input stage. The N-channel-JFET input stage allows a common-mode input voltage range that includes the negative supply voltage and offers a typical input impedance of $10^{12}\,\Omega$, a typical input offset current of 50 pA, and a typical input bias current of 200 pA. This device is designed to operate from a single supply over a range of 3 V to 36 V. Operation from split supplies also is possible, provided the difference between the two supplies is 3 V to 36 V. Output voltage range is from V_{CC}– to V_{CC+} – 1.3 V, with a load resistor to V_{CC-}.

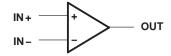
The TL092 is characterized for operation from 0°C to 70°C.

AVAILABLE OPTIONS

	PACKAGED DEVICE
TA	PLASTIC SMALL OUTLINE (PS)
0°C to 70°C	TL092CPSR

The PS package is only available taped and reeled. Add the suffix R to device type for ordering (e.g., TL092CPSR).

symbol

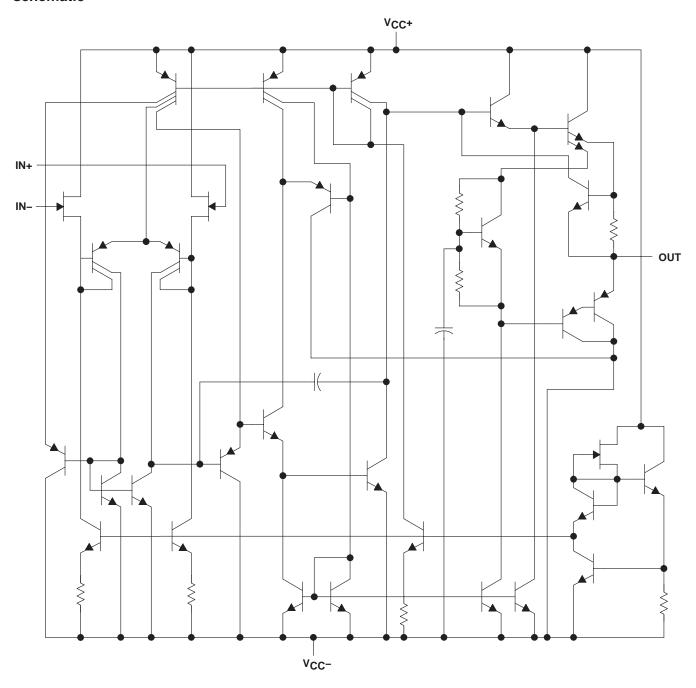




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schematic





TL092 DUAL JFET-INPUT OPERATIONAL AMPLIFIER

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

5	Supply voltage: V _{CC+} (see Note 1)	18 V
	V _{CC} – (see Note 1)	–18 V
	V _{CC+} with respect to V _{CC-}	36 V
	Differential input voltage, V _{ID} (see Note 2)	±36 V
I	nput voltage, V _I (see Notes 1 and 3)	±18 V
F	Package thermal impedance, θ_{JA} (see Notes 4 and 5) \dots	95°C/W
L	Lead temperature 1.6 mm (1/16 inch) from case for 10 seconds	260°C
5	Storage temperature range, T _{stg}	-65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-}.
 - 2. Differential voltages are at the noninverting input with respect to the inverting input.
 - 3. Neither input must ever be more positive than $\,V_{CC+}$ or more negative than $\,V_{CC-}$ 0.3 V.
 - Maximum power dissipation is a function of T_J(max), θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is P_D = (T_J(max) T_A)/θ_{JA}. Operating at the absolute maximum T_J of 150°C can impact reliability.
 - 5. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions

		MIN	MAX	UNIT
VCC±	Supply voltage	3	36	V
TA	Operating free-air temperature range	0	70	°C



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electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ± 15 V (all characteristics are specified under open-loop conditions, unless otherwise noted)

	PARAMETER	TES	ST CONDITIONS	TA	MIN	TYP	MAX	UNIT
		B 50.0		25°C		5	15	.,
V _{IO}	Input offset voltage	$R_S = 50 \Omega$		Full range			20	mV
αVIO	Temperature coefficient of input offset voltage			25°C		10		μV/°C
. +	level offert comment			25°C		50	200	рА
110‡	Input offset current			Full range			5	nA
. +	Level Idea comment			25°C		200	400	pA
I _{IB} ‡	Input bias current			Full range			10	nA
VICR	Common-mode input voltage range			25°C	V _{CC} - to 12	V _{CC} - to 13		V
	Peak output voltage swing	$R_L = 2 k\Omega$		25°C	±10	±13		
VO(PP)		$R_L = 10 \text{ k}\Omega$		25°C	±12	±13.5		V
` '		$R_L = 2 k\Omega$		Full range	±10			
Δ	Large-signal differential voltage amplification	D. O.L.O.	\/o - ±10 \/	25°C	20	200		\//m\/
AVD		$R_L = 2 k\Omega$,	V _O = ±10 V	Full range	15			V/mV
ВОМ	Maximum output swing bandwidth	$R_L = 2 k\Omega$, $A_{VD} = 1$,	V _{O(PP)} = 20 V, THD < 5%	25°C		9		kHz
В1	Unity gain bandwidth	$R_L = 10 \text{ k}\Omega$,	$V_O = 50 \text{ mV}$	25°C		1		MHz
φm	Phase margin	$R_L = 2 k\Omega$,	C _L = 200 pF	25°C		60°		
rį	Input resistance	f = 20 Hz		25°C		10 ¹²		Ω
r _O	Output resistance	f = 20 Hz		25°C		75		Ω
CMRR	Common-mode rejection ratio	$R_S = 50 \Omega$,	V _{IC} = V _{ICR}	25°C	70	90		dB
ksvr	Supply-voltage rejection ratio (ΔV _{CC} /ΔV _{IO})	$R_S = 50 \Omega$,	$V_{CC\pm} = \pm 3 \text{ V to } \pm 15 \text{ V}$	25°C	75	90		dB
los	Short-circuit output current			25°C		40		mA
Icc	Supply current (per amplifier)	V _O = 0,	No load	25°C		1.5	2.5	mA

electrical characteristics at specified free-air temperature, V_{CC+} = 5 V, V_{CC-} = 0 V, T_A = 25°C (unless otherwise noted)

	PARAMETER	TE	EST CONDITIONS	MIN	TYP [†]	MAX	UNIT
V _{IO}	Input offset voltage	$R_S = 50 \Omega$,	V _O = 2.5 V		5	15	mV
lio	Input offset current	V _O = 2.5 V			50	200	рА
I _{IB}	Input bias current	V _O = 2.5 V			200	400	рА
V _{O(PP)}	Peak output voltage swing	$R_L = 10 \text{ k}\Omega$		3.3	3.5		V
		$R_L = 10 \text{ k}\Omega$,	$V_{CC+} = 5 \text{ V to } 30 \text{ V}$	V _{CC+} -1.7			V
AVD	Large-signal differential voltage amplification	$R_L = 2 k\Omega$,	ΔV _O =1.6 V	20	200		V/mV
k _{SVR}	Supply-voltage rejection ratio (ΔV _{CC} /ΔV _{IO})	$R_S = 50 \Omega$,	$V_{CC\pm} = \pm 3 \text{ V to } \pm 15 \text{ V}$	75			dB
Icc	Supply current (per amplifier)	V _O = 2.5 V,	No load		1.5	2.5	mA
V _{O1} /V _{O2}	Channel separation	f = 1 kHz to 20 l	кНz		120		dB

[†] All typical values are at $T_A = 25$ °C.



[†] All typical values are at T_A = 25°C. ‡ Input bias currents of a FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive. Pulse techniques that maintain the junction temperature as close to the ambient temperature as possible must be used.

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operating characteristics, $V_{CC\pm}$ = ± 15 V, T_A = $25^{\circ}C$

PARAMETER TEST CONDITIONS			MIN	TYP	MAX	UNIT		
SR	Slew rate at unity gain	$V_I = \pm 10 \text{ V (see Figure 1)},$	C _L = 100 pF,	$R_L = 2 k\Omega$		0.6		V/μs
t _r	Rise time	ΔV_{O} = 50 mV (see Figure 1),	$C_L = 100 pF$,	$R_L = 2 k\Omega$		0.2		μs
t _f	Fall time	ΔV_{O} = 50 mV (see Figure 1),	$C_L = 100 pF$,	$R_L = 2 k\Omega$		0.2		μs
	Overshoot factor	ΔV_{O} = 50 mV (see Figure 1),	C _L = 100 pF,	$R_L = 2 k\Omega$		20%		
	Crossover distortion	$V_{IPP} = 30 \text{ mV}, V_{O(PP)} = 2 \text{ V},$	f = 10 kHz			1%		
Vn	Equivalent input noise voltage	R _S = 100 Ω,	f = 1 kHz			34		nV/√ Hz

PARAMETER MEASUREMENT INFORMATION

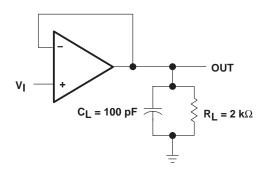


Figure 1. Unity-Gain Amplifier

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